Development Board EPC9001C Quick Start Guide

40 V Half-Bridge with Gate Drive, Using EPC2015C



QUICK START GUIDE EPC90010

DESCRIPTION www.epc-co.com

The EPC9001C development board is a 40 V maximum device voltage, 15 A maximum output current, half bridge with onboard gate drives, featuring the EPC2015C enhancement mode (eGaN®) field effect transistor (FET). The purpose of this development board is to simplify the evaluation process of the EPC2015C eGaN FET by including all the critical components on a single board that can be easily connected into any existing converter.

The EPC9001C development board is 2" x 1.5" and contains two EPC2015Cs eGaN FET in a half bridge configuration using Texas Instruments LM5113 gate driver, supply and bypass capacitors. The board contains all critical components and layout for optimal switching performance. There are also various probe points to facilitate simple waveform measurement and efficiency calculation. A complete block diagram of the circuit is given in Figure 1.

For more information on the EPC2015Cs eGaN FET please refer to the datasheet available from EPC at www.epc-co.com. The datasheet should be read in conjunction with this quick start guide.

Table 1: Performance Summary (TA = 25°C)									
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS				
V _{DD}	Gate Drive Input Supply Range		7	12	V				
V _{IN}	Bus Input Voltage Range			28*	V				
V _{out}	Switch Node Output Voltage			40	V				
I _{out}	Switch Node Output Current			15*	А				
V _{PWM}	PWM Logic Input Voltage Threshold	Input 'High'	3.5	6	V				
		Input'Low'	0	1.5	V				
	Minimum 'High' State Input Pulse Width	VPWM rise and fall time < 10ns	60		ns				
	Minimum 'Low' State Input Pulse Width	VPWM rise and fall time < 10ns	200#		ns				

^{*} Assumes inductive load, maximum current depends on die temperature – actual maximum current with be subject to switching frequency, bus voltage and thermals.

Quick Start Procedure

Development board EPC9001C is easy to set up to evaluate the performance of the EPC2015C eGaN FET. Refer to Figure 2. for proper connect and measurement setup and follow the procedure below:

- 1. With power off, connect the input power supply bus to $+V_{IN}$ (J5, J6) and ground / return to $-V_{IN}$ (J7, J8).
- 2. With power off, connect the switch node of the half bridge OUT (J3, J4) to your circuit as required.
- 3. With power off, connect the gate drive supply to $+V_{DD}$ (J1, Pin-1) and ground return to $-V_{DD}$ (J1, Pin-2).
- 4. With power off, connect the input PWM control signal to PWM (J2, Pin-1) and ground return to any of the remaining J2 pins.
- 5. Turn on the gate drive supply make sure the supply is between 7 V and 12 V range.
- 6. Turn on the bus voltage to the required value (do not exceed the absolute maximum voltage of 100 V on V_{OUT}).
- 7. Turn on the controller / PWM input source and probe switching node to see switching operation.
- Once operational, adjust the bus voltage and load PWM control within the operating range and observe the output switching behavior, efficiency and other parameters.
- 9. For shutdown, please follow steps in reverse.

NOTE. When measuring the high frequency content switch node (OUT), care must be taken to avoid long ground leads. Measure the switch node (OUT) by placing the oscilloscope probe tip through the large via on the switch node (designed for this purpose) and grounding the probe directly across the GND terminals provided. See Figure 3 for proper scope probe technique.

THERMAL CONSIDERATIONS

The EPC9001C development board showcases the EPC2015C eGaN FET. Although the electrical performance surpasses that for traditional silicon devices, their relatively smaller size does magnify the thermal management requirements. The EPC9001C is intended for bench evaluation with low ambient temperature and convection cooling. The addition of heat-sinking and forced air cooling can significantly increase the current rating of these devices, but care must be taken to not exceed the absolute maximum die temperature of 150°C.

NOTE. The EPC2015C development board does not have any current or thermal protection on board.

[#] Limited by time needed to 'refresh' high side bootstrap supply voltage.

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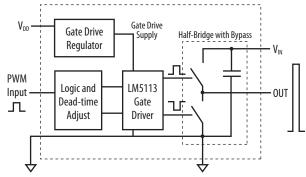


Figure 1: Block Diagram of EPC9001C Development Board

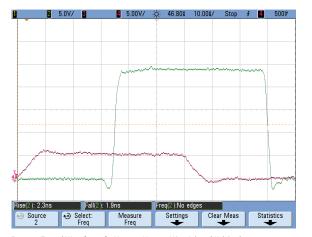


Figure 4: Typical Waveforms for $V_{IN} = 24 \text{ V}$ to 1.2 V/15 A (500 kHz) Buck converter CH1: VPWM Input voltage — CH3: (lout) Switch node current — CH4: (Vout) Switch node voltage

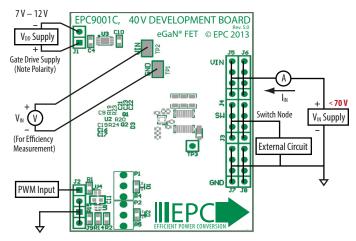


Figure 2: Proper Connection and Measurement Setup

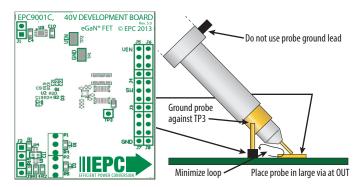
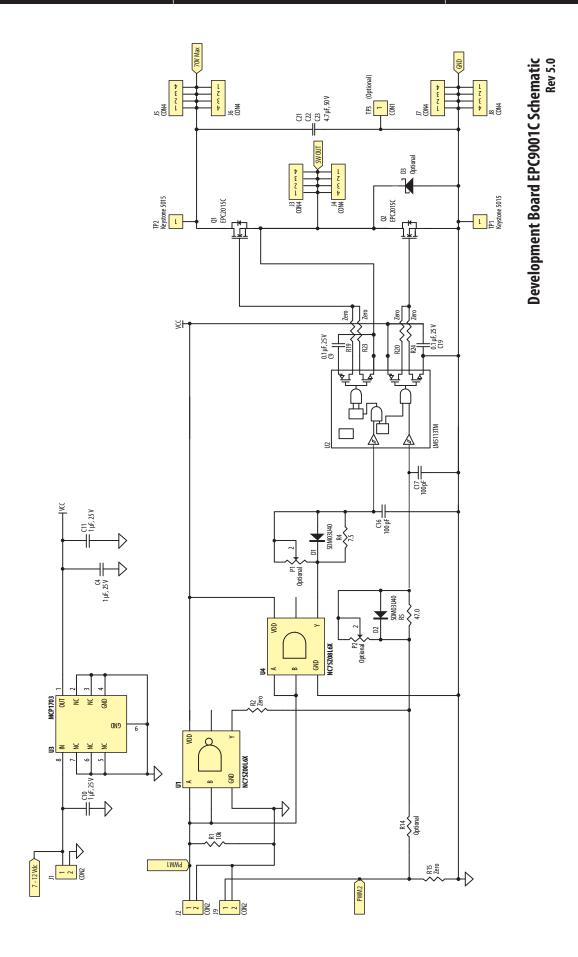


Figure 3: Proper Measurement of Switch Node — OUT

able 2 : Bill of Material					
ltem	Qty	Reference	Part Description	Manufacturer / Part #	
1	3	C4, C10, C11,	Capacitor, 1 μF, 10%, 25 V, X5R	Murata, GRM188R61E105KA12D	
2	2	C16, C17	Capacitor, 100 pF, 5%, 50 V, NP0	Kemet, C0402C101K5GACTU	
3	2	C9, C19	Capacitor, 0.1 μF, 10%, 25 V, X5R	TDK, C1005X5R1E104K	
4	3	C21, C22, C23	Capacitor, 4.7 μF, 10%, 50 V, X5R	TDK, C2012X5R1H475K125AB	
5	2	D1, D2	Schottky Diode, 30 V	Diodes Inc., SDM03U40-7	
6	3	J1, J2, J9	Connector	2pins of Tyco, 4-103185-0	
7	1	J3, J4, J5, J6, J7, J8	Connector	FCI, 68602-224HLF	
8	2	Q1, Q2	eGaN® FET	EPC, EPC2015C	
9	1	R1	Resistor, 10.0 K, 5%, 1/8 W	Stackpole, RMCF0603FT10K0	
10	2	R2, R15	Resistor, 0 Ohm, 1/8 W	Stackpole, RMCF0603ZT0R00	
11	1	R4	Resistor, 7.5 Ohm, 1%, 1/8 W	Stackpole, RMCF0603FT7R50	
12	1	R5	Resistor, 47 Ohm, 1%, 1/8 W	Stackpole, RMCF0603FT47R0	
13	6	R19, R20, R21, R22, R23, R24	Resistor, 0 Ohm, 1/16 W	Stackpole, RMCF0402ZT0R00	
14	2	TP1,TP2	Test Point	Keystone Elect, 5015	
15	1	TP3	Connector	1/40th of Tyco, 4-103185-0	
16	1	U1	I.C., Logic	Fairchild, NC7SZ00L6X	
17	1	U2	I.C., Gate driver	Texas Instruments, LM5113TME	
18	1	U3	I.C., Regulator	Microchip, MCP1703T-5002E/MC	
19	1	U4	I.C., Logic	Fairchild, NC7SZ08L6X	
20	0	R14	Optional Resistor		
21	0	D3	Optional Diode		
22	0	P1, P2	Optional Potentiometer		

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